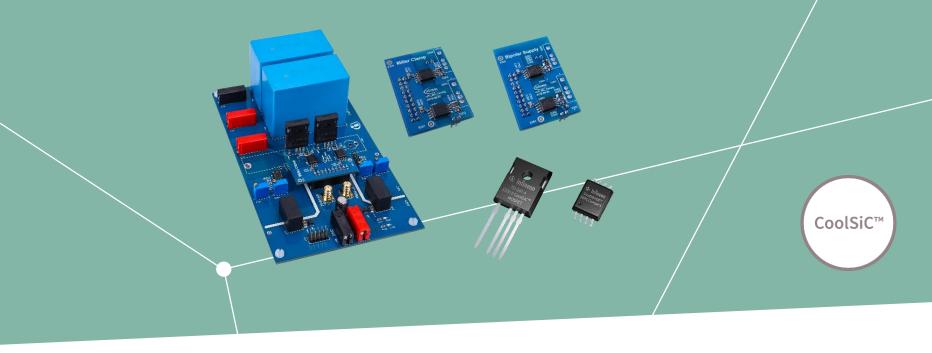
Operation Manual for CoolSiC™ MOSFET 1200 V evaluation platform including EiceDRIVER™ gate driver IC







- 1 Introduction
- 2 Key features of mother board and two daughter boards
- Let's get started operation manual
- 4 Schematics
- 5 Order information
- 6 Support materials

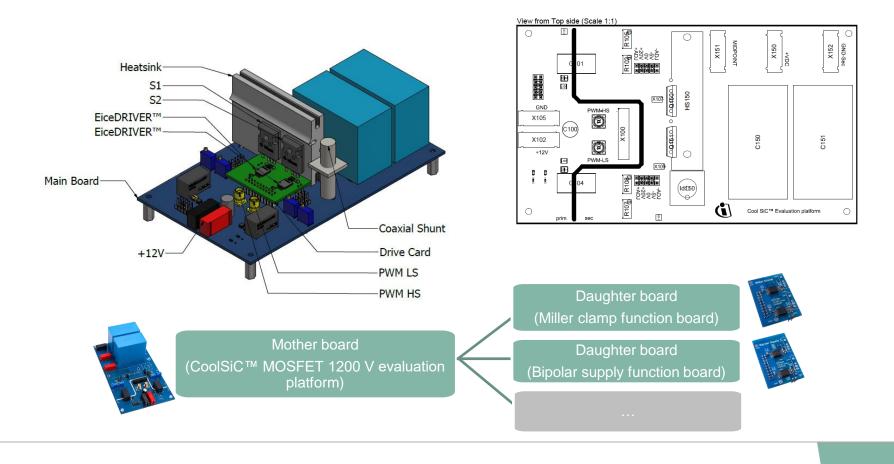


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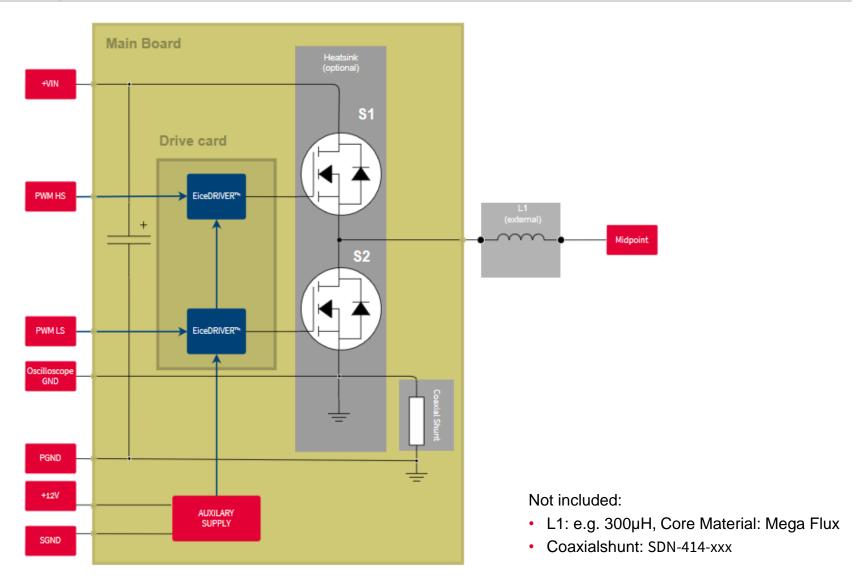
Introduction

The kit "CoolSiC™ MOSFET 1200 V evaluation platform including EiceDRIVER™ gate driver IC" consists of **1x mother board** (a modular characterization platform), **2x daughter boards** (drive cards/function boards), **4x IMZ120R045M1** (CoolSiC™ MOSFET 1200 V 45mΩ in TO-247-4)





Block diagram





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Key features of mother board and two daughter boards

CoolSiC™ MOSFET 1200 V evaluation platform

- V_{CC2} gate drive voltage supply from -5 V to +20 V
- V_{CC1} supply fixed at +5 V
- Gate connection via SMA-BNC connector
- Current measurement via optional Coaxialshunt
- Optimized commutation loop
- External load inductor connection



Miller clamp board

- Wide body package (300 mil)
- Minimal gate drive loop
- > Rg-ON and Rg-OFF changeable
- V_{CC2} +15 V to 0V GND
- Active miller clamp function

Bipolar supply board

- Wide body package (300 mil)
- Minimal gate drive loop
- > Rg-ON and Rg-OFF changeable
- V_{CC2} +15 V to -5 V GND2
- Possibility for negative power supply





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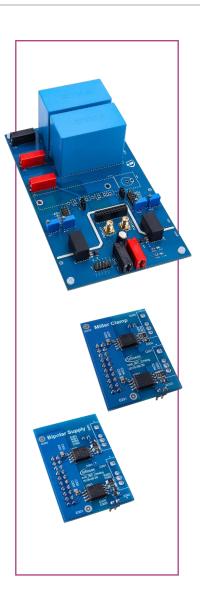
Let's get started – operation manual

- Mount drive card on motherboard and set the jumpers for the needed supply voltage
- Solder the DUTs and the Coaxial shunt on the platform. For other current measurements bridge Id150
- Connect Power source (VDC up to 800V), Auxiliary supply 12V, function generator (for double pulse)
- Connect the load inductor, either HS or LS
- Plug the wanted probes (voltage, current)

To turn on:

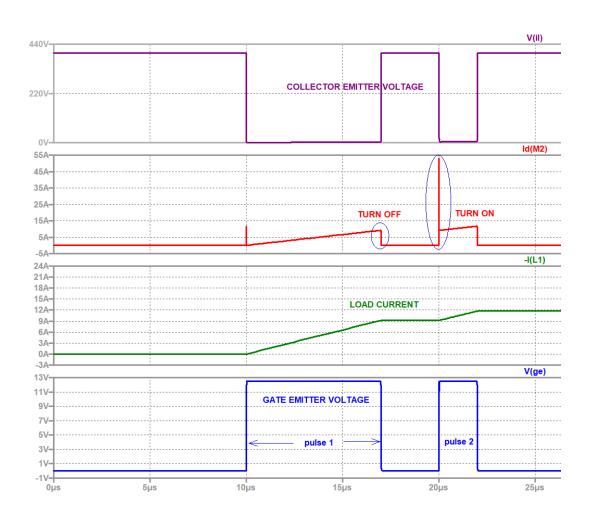
- Apply 12V and double pulse, then apply high voltage stepwise until wanted level. Start the measurement.
- To turn off:

 Switch off the high voltage source, then switch off Aux supply and function generator.





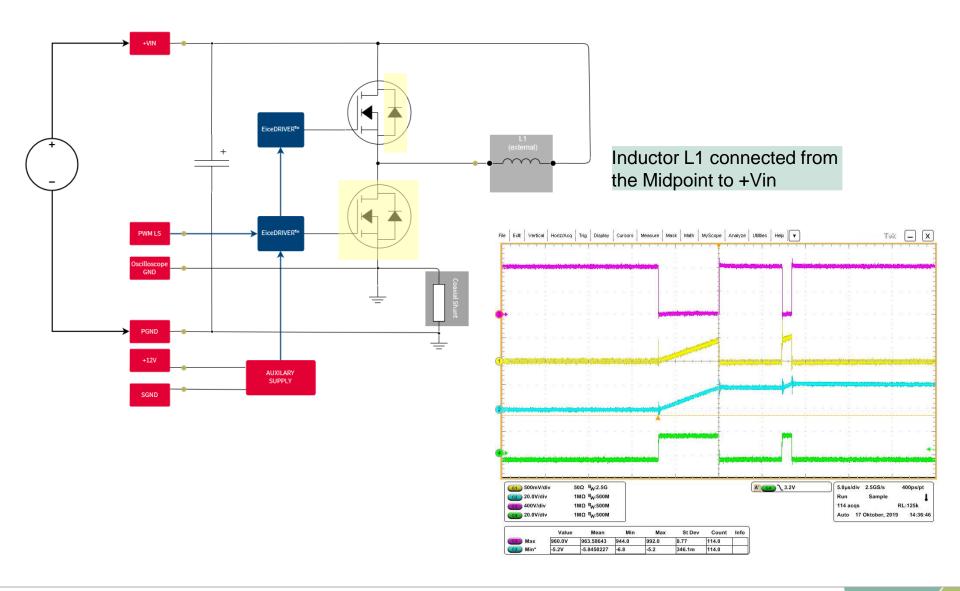
Double Pulse principle



The pulse 1 width defines the desired current in the inductive load. The turn-off event of pulse 1 leads to a constant current through the body diode of S1, which can be also replaced by a discrete diode. Turn-on of pulse 2 shows the reverse recovery charge of S1 or the respective diode.

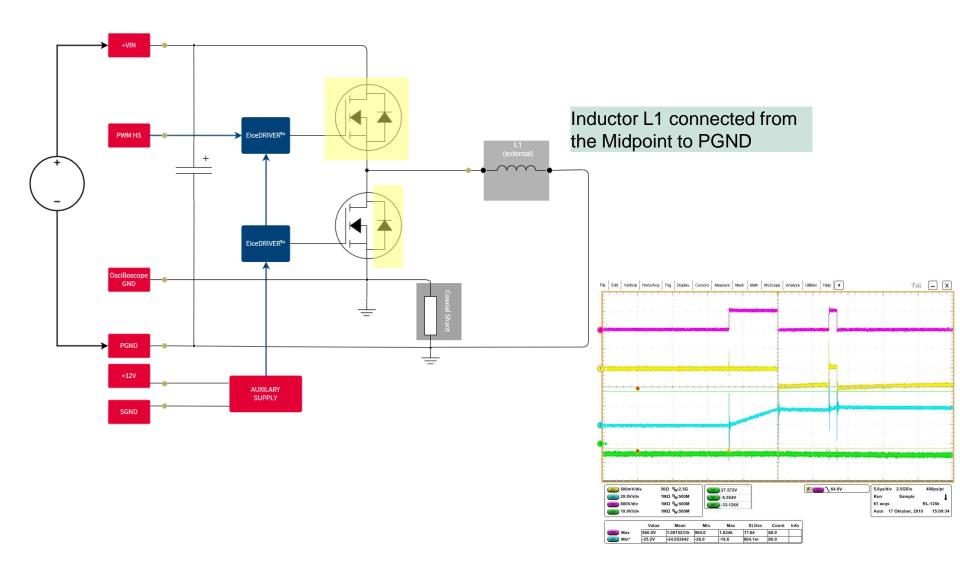


Half Bridge configuration for LS MOSFET or HS Diode testing





Half Bridge configuration for HS MOSFET or LS Diode testing

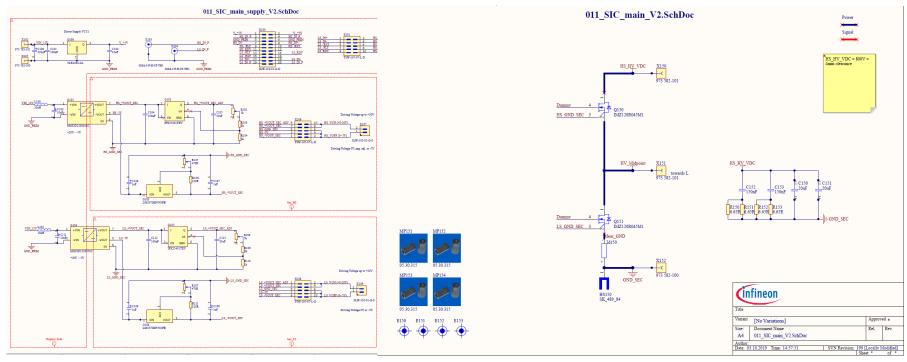




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Schematic of CoolSiC™ MOSFET 1200 V evaluation platform

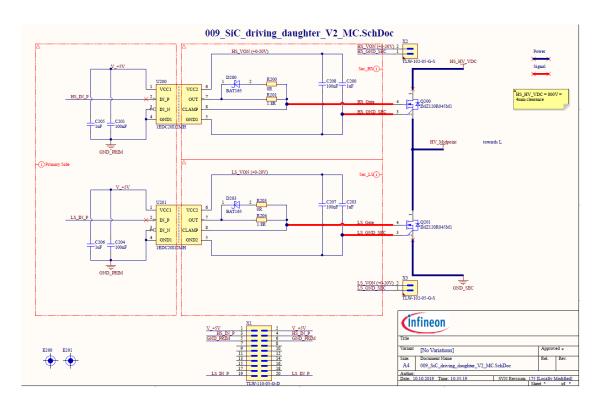








Schematic of Miller clamp function board



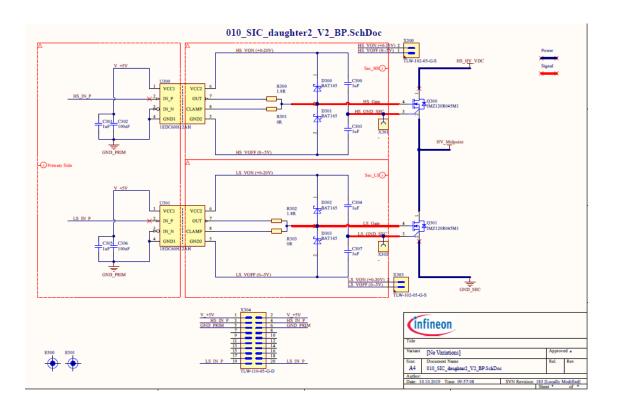


Jumper Settings on the Main board

Case	+ADJ	+20V	OV	-5V	-ADJ
1	Χ		Χ		
2		Х	Χ		



Schematic of Bipolar supply function board





Jumper Settings on the Main board

Case	+ADJ	+20V	0V	-5V	-ADJ
1	Х			Х	
2	Х				Х
3		Х		Х	
4		Х			Х



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Order information

Product description name	CoolSiC™ MOSFET 1200 V evaluation platform including EiceDRIVER™ gate driver IC	Miller clamp function board for CoolSiC™ MOSFET 1200 V evaluation platform	Bipolar supply function board for CoolSiC™ MOSFET 1200 V evaluation platform
Sales product name	EVAL_PS_SIC_DP_MAIN	REF_PS_SIC_DP1	REF_PS_SIC_DP2
OPN	EVALPSSICDPMAINTOBO1	REFPSSICDP1TOBO1	REFPSSICDP2TOBO1
SP number	SP005412616	SP005412618	SP005412619
Content	 Mother board (CoolSiC™ MOSFET 1200 V evaluation platform) – 1pc Daughter boards (Miller clamp and bipolar supply boards) – 1pc each (total 2pcs) IMZ120R045M1 (CoolSiC™ MOSFET 1200 V 45mΩ in TO-247-4) – 4pcs 	 Daughter board (Miller clamp function board) – 1pc IMZ120R045M1 (CoolSiC™ MOSFET 1200 V 45mΩ in TO-247-4) – 2pcs 	 Daughter board (Bipolar supply function board) – 1pc IMZ120R045M1 (CoolSiC™ MOSFET 1200 V 45mΩ in TO-247-4) – 2pcs



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Support materials

Datasheet -

Technical -

- Application note
 - User Manual for CoolSiC™ MOSFET 1200 V evaluation platform including EiceDRIVER™ gate driver IC coming soon
 - Guide for CoolSiC™ MOSFET gate drive voltage window
 - Introduction to CoolSiC[™] 1200 V SiC MOSFET
 - Advanced gate drive options for silicon carbide (SiC) MOSFETs
- Application Brochure
 - Gate driver application matrix Every switch needs a driver
- Fighting guide
 - CoolSiC™ 1200 V discrete MOSFET fighting guide coming soon
- Articles
 - SiC MOSFETs for Bridge Topologies in Three-Phase Power Conversion
 - CoolSiC™ MOSFET technology: a revolution for power conversion systems
 - A SiC MOSFET for Mainstream Adoption

Online support -

- Infineon CoolSiC[™] forum
- Infineon CoolSiC™ MOSFET discretes webpage



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